# **General Purpose Transistors**

## **PNP Silicon**

### Features

• These are Pb–Free Devices

### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V <sub>CEO</sub>	-60	Vdc
Collector-Base Voltage	V <sub>CBO</sub>	-60	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	-5.0	Vdc
Collector Current – Continuous	Ι <sub>C</sub>	-600	mAdc

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1) @T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) @T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

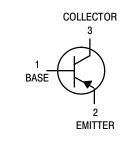
1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.

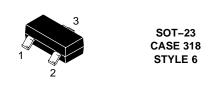
2. Alumina = 0.4  $\times$  0.3  $\times$  0.024 in. 99.5% alumina.



## **ON Semiconductor®**

### http://onsemi.com





### MARKING DIAGRAM



297 = Specific Device Code

M = Date Code\*

= Pb–Free Package

(Note: Microdot may be in either location) \*Date Code orientation and/or overbar may vary depending upon manufacturing location.

### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NSCT2907ALT1G	SOT-23 (Pb-Free)	3000 Tape & Reel
NSCT2907ALT3G	SOT-23 (Pb-Free)	10,000 Tape & Reel

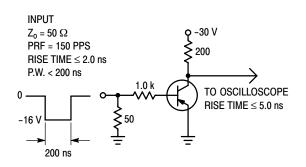
<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

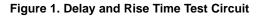
### **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

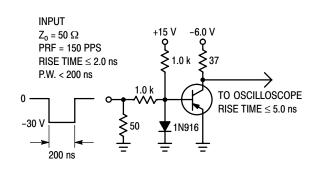
Character	Symbol	Min	Max	Unit	
OFF CHARACTERISTICS					
Collector-Emitter Breakdown Voltage (Note 3	V <sub>(BR)CEO</sub>	-60	-	Vdc	
Collector – Base Breakdown Voltage ( $I_C = -$	V <sub>(BR)CBO</sub>	-60	-	Vdc	
Emitter – Base Breakdown Voltage ( $I_E = -10$	V <sub>(BR)EBO</sub>	-5.0	-	Vdc	
Collector Cutoff Current (V <sub>CE</sub> = $-30$ Vdc, V <sub>E</sub>	B(off) = -0.5 Vdc)	I <sub>CEX</sub>	_	-50	nAdc
Collector Cutoff Current ( $V_{CB} = -50$ Vdc, $I_E = 0$ ) ( $V_{CB} = -50$ Vdc, $I_E = 0$ , $T_A = 125^{\circ}C$ )	I <sub>CBO</sub>		-0.010 -10	μAdc	
Base Cutoff Current (V <sub>CE</sub> = $-30$ Vdc, V <sub>EB(off</sub>	I <sub>BL</sub>	-	-50	nAdc	
ON CHARACTERISTICS					
DC Current Gain $(I_{C} = -0.1 \text{ mAdc}, V_{CE} = -10 \text{ Vdc})$ $(I_{C} = -1.0 \text{ mAdc}, V_{CE} = -10 \text{ Vdc})$ $(I_{C} = -10 \text{ mAdc}, V_{CE} = -10 \text{ Vdc})$ $(I_{C} = -150 \text{ mAdc}, V_{CE} = -10 \text{ Vdc})$ $(I_{C} = -500 \text{ mAdc}, V_{CE} = -10 \text{ Vdc})$ (Note 3)	3)	h <sub>FE</sub>	75 100 100 100 50	- - 300 -	_
Collector – Emitter Saturation Voltage (Note $(I_C = -150 \text{ mAdc}, I_B = -15 \text{ mAdc})$ (Note 3 $(I_C = -500 \text{ mAdc}, I_B = -50 \text{ mAdc})$	,	V <sub>CE(sat)</sub>		-0.4 -1.6	Vdc
$\begin{array}{l} \text{Base}-\text{Emitter Saturation Voltage (Note 3)} \\ (I_C = -150 \text{ mAdc}, I_B = -15 \text{ mAdc}) \\ (I_C = -500 \text{ mAdc}, I_B = -50 \text{ mAdc}) \end{array}$	V <sub>BE(sat)</sub>		-1.3 -2.6	Vdc	
SMALL-SIGNAL CHARACTERISTICS					
Current-Gain – Bandwidth Product (Notes f = 100 MHz)	3, 4), (I <sub>C</sub> = -50 mAdc, V <sub>CE</sub> = -20 Vdc,	f <sub>T</sub>	200	-	MHz
Output Capacitance ( $V_{CB} = -10$ Vdc, $I_E = 0$	, f = 1.0 MHz)	C <sub>obo</sub>	_	8.0	pF
Input Capacitance (V <sub>EB</sub> = $-2.0$ Vdc, I <sub>C</sub> = 0,	C <sub>ibo</sub>	_	30		
SWITCHING CHARACTERISTICS	<b>·</b>			•	
Turn-On Time		t <sub>on</sub>	_	45	
Delay Time	$(V_{CC} = -30 \text{ Vdc}, I_C = -150 \text{ mAdc}, I_{B1} = -15 \text{ mAdc})$	t <sub>d</sub>	-	10	1
Rise Time	.DI - 10 11/100/	t <sub>r</sub>	-	40	
Turn-Off Time		t <sub>off</sub>	-	100	ns
Storage Time $(V_{CC} = -6.0 \text{ Vdc}, I_C = -150 \text{ mAdc}, I_{B1} = I_{B2} = -15 \text{ mAdc})$		ts	-	80	1
Fall Time	·B1 ·B2 · · · · · · · · · · · · · · · · · ·	t <sub>f</sub>	_	30	1

3. Pulse Test: Pulse Width  $\leq$  300 µs, Duty Cycle  $\leq$  2.0%.

4.  $f_T$  is defined as the frequency at which  $|h_{fe}|$  extrapolates to unity.

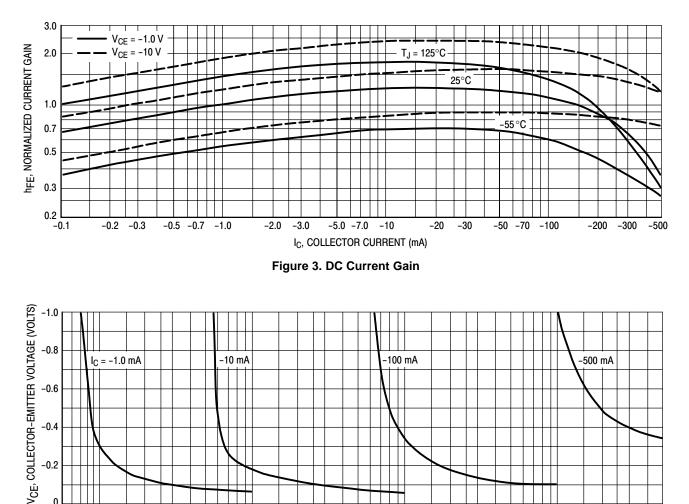


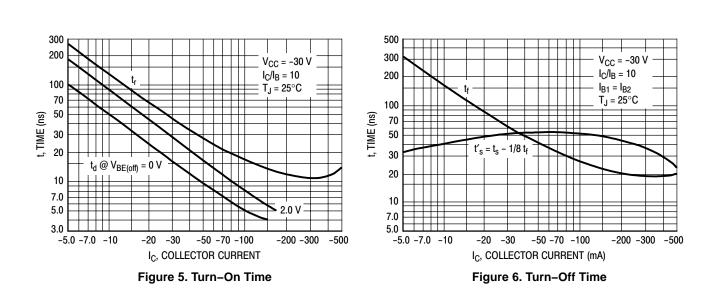






### **TYPICAL CHARACTERISTICS**





-0.5 -0.7 -1.0

IB, BASE CURRENT (mA)

Figure 4. Collector Saturation Region

-2.0

-3.0

-5.0 -7.0 -10

-20 -30 -50

-0.2 -0.3

-0.2

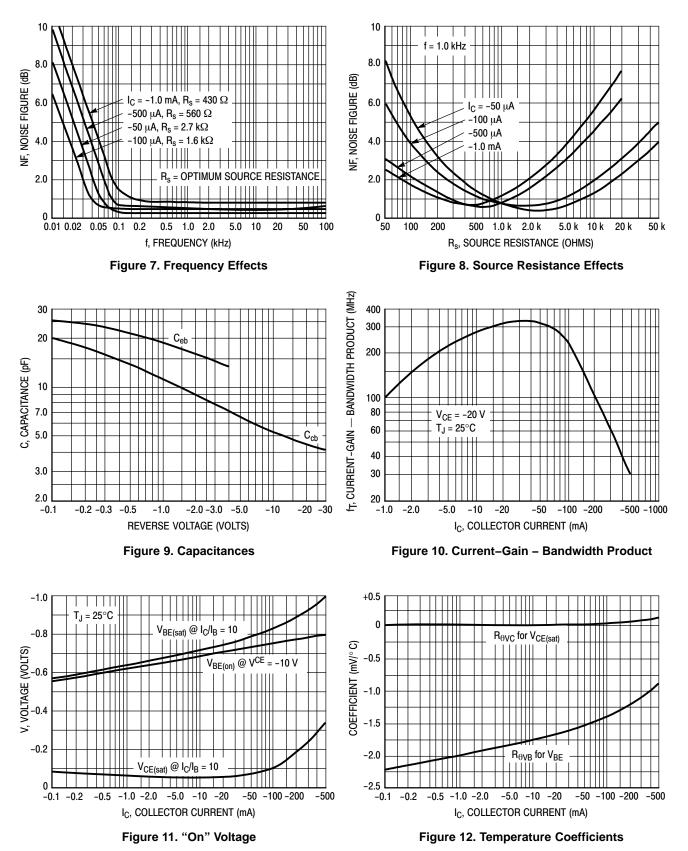
0 -0.005

-0.01

-0.02 -0.03 -0.05 -0.07 -0.1

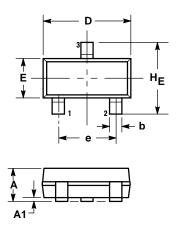
### TYPICAL SMALL-SIGNAL Characteristics NOISE FIGURE

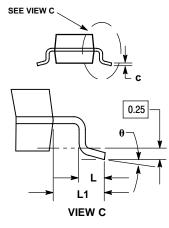
 $V_{CE}$  = 10 Vdc,  $T_A$  = 25°C



#### PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 ISSUE AN





NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
   CONTROLLING DIMENSION: INCH.
- CONTROLLING DIMENSION: INCH.
  MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- 4. 318–01 THRU –07 AND –09 OBSOLETE, NEW STANDARD 318–08.

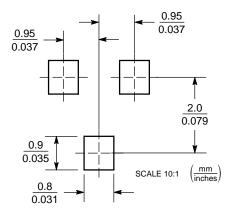
	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
С	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
Е	1.20	1.30	1.40	0.047	0.051	0.055
e	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104

STYLE 6:

PIN 1. BASE 2. EMITTER

3. COLLECTOR

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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